学位論文要約

Experimental determination of electronic structures of superconductors $ZrP_{2-x}Se_x$ and $Nb_3Y(Y = Al, Sn)$

(超伝導体 ZrP_{2-x}Se_x および Nb₃Y (Y = Al, Sn)の電子構造の実験的決定)

石坂 仁志

Department of Physics, Graduate School of Science, Hiroshima University

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